NSN 5961-01-059-1663

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View Online at https://aerobasegroup.com/nsn/5961-01-059-1663 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 20.0 emitter to base voltage, static, collector open and 20.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 15.00 amperes source cutoff current **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius case **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

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